



NPN SMALL SIGNAL TRANSISTOR IN SOT323

Features

- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856W BC858W
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

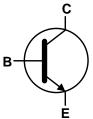
Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)

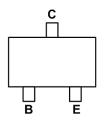








Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 & 5)

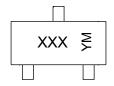
Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC846AW-7-F	AEC-Q101	K1Q	7	3,000
BC846BW-7-F	AEC-Q101	K1R	7	3,000
BC846BWQ-7-F	Automotive	K1R	7	3,000
BC846BW-13-F	AEC-Q101	K1R	13	10,000
BC847AW-7-F	AEC-Q101	K1Q	7	3,000
BC847BW-7-F	AEC-Q101	K1R	7	3,000
BC847BW-13-F	AEC-Q101	K1R	13	10,000

Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC847BWQ-13-F	Automotive	K1R	13	10,000
BC847CW-7-F	AEC-Q101	K1M	7	3,000
BC847CW-13-F	AEC-Q101	K1M	13	10,000
BC847CWQ-7-F	Automotive	K1M	7	3,000
BC848AW-7-F	AEC-Q101	K1Q	7	3,000
BC848BW-7-F	AEC-Q101	K1R	7	3,000
BC848CW-7-F	AEC-Q101	K1M	7	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



XXX = Product Type Marking Code (Please see Ordering Information) YM = Date Code Marking

Y or \overline{Y} = Year (ex: E = 2017) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2016		2017	2018		2019	2020		2021	2022		2023
Code	D		E	F		G	Н			J		K
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Character	istic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V_{CBO}	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V_{CEO}	45	V
	BC848		30	
Emitter Page Voltage	BC846, BC847	6		V
Emitter-Base Voltage	BC848	V _{EBO}	5	v
Continuous Collector Current		Ic	100	mA
Peak Collector Current		Ісм	200	mA
Peak Base Current		I _{BM}	200	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	P _D	200	mW
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{6.} For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Chai	racteristic			Symbol	Min	Тур	Max	Unit	Test Condition	
		Е	3C846		80					
Collector-Base Breakdown Voltage		Е	BC847	BV _{CBO}	50	_	_	V	$I_{C} = 100 \mu A$	
		E	BC848		30					
		Е	BC846		65					
Collector-Emitter Breakdown \	/oltage (Note 8)	Е	BC847	BV _{CEO}	45	_	_	V	$I_C = 10mA$	
		Е	BC848		30					
Emitter-Base Breakdown Volta	ane	BC8	46, BC847	BV _{EBO}	6	_	_	V	I _E = 100μA	
Emitter Base Breakdown voite		Е	BC848	DAERO	5			V	ΙΕ = 100μΑ	
			Α		110	180	220			
DC Current Gain (Note 8)	Current Gain G	roup	В	h _{FE}	200	290	450	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$	
			С		420	520	800			
Collector Cutoff Current				I _{CBO} —			20	nA	V _{CB} = 30V	
Collector Cutoff Current					_	5	μA	V _{CB} = 30V, T _A = +150°C		
Collector-Emitter Saturation Vo	oltago (Noto 9)			V _{CE(sat)}		90	250	mV	$I_C = 10mA, I_B = 0.5mA$	
Collector-Emitter Saturation V	oliage (Note 6)				1	200	600	111 V	$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$	
Base-Emitter Turn-On Voltage	(Note 9)			\/·	580	660	700	mV	$I_C = 2mA$, $V_{CE} = 5V$	
Base-Emiller Turn-On Vollage	(Note o)			V _{BE(on)}	1	_	770	IIIV	$I_C = 10$ mA, $V_{CE} = 5$ V	
Base-Emitter Saturation Voltage	go (Noto 9)			\/·		700	_ mV		$I_C = 10mA, I_B = 0.5mA$	
Dase-Emiller Saluration Voltag	ge (Note 6)			V _{BE(sat)}		900		IIIV	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$	
Output Capacitance				C _{obo}		3	4.5	pF	V _{CB} = 10V, f = 1.0MHz	
Transition Frequency			f⊤	100	300	_	MHz	$V_{CE} = 5V, I_{C} = 10mA,$ f = 100MHz		
Noise Figure			NF	_	_	10	dB	V_{CE} = 5V, I_{C} = 200 μ A R_{S} = 2 $k\Omega$, f = 1 k Hz Δf = 200Hz		

Note:

8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

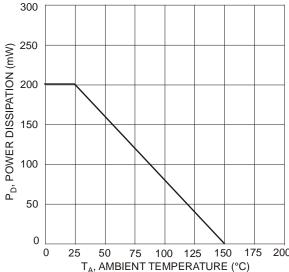


Figure 1 Power Dissipation vs. Ambient Temperature

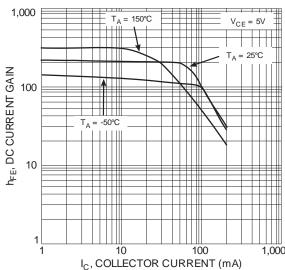


Figure 3 Typical DC Current Gain vs. Collector Current
(Band A Group Gain)

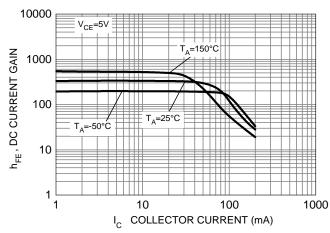


Figure 5 Typical DC Current Gain vs. Collector Current (Band B Group Gain)

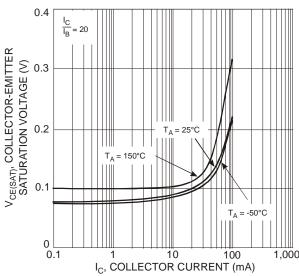


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

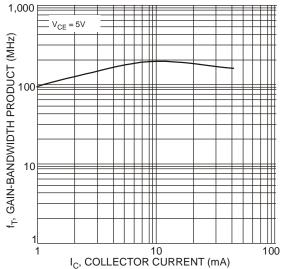


Figure 4 Typical Gain-Bandwidth Product vs. Collector Current

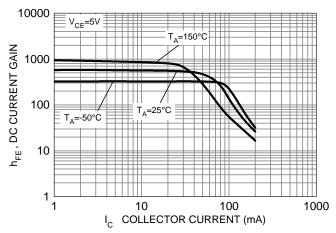
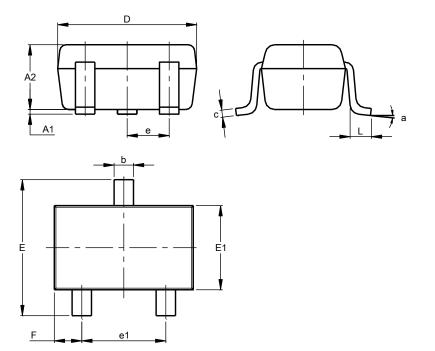


Figure 6 Typical DC Current Gain vs. Collector Current (Band C Group Gain)



Package Outline Dimensions

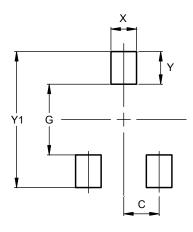
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323								
Dim	Min Max Typ							
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
С	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	0).650 B	SC					
e1	1.20	1.40	1.30					
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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